January 2005

FAIRCHILD SEMICONDUCTOR®

BDW94/C PNP Epitaxial Silicon Transistor

Power Linear and Switching Application

- Power Darlington TR
- Complement to BDW93 and BDW93C Respectively



1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage		
	: BDW94	-45	V
	: BDW94C	-100	V
V _{CEO}	Collector-Emitter Voltage		
	: BDW94	-45	V
	: BDW94C	-100	V
I _C	Collector Current (DC)	-12	A
I _{CP}	Collector Current (Pulse) *	-15	A
I _B	Base Current	-0.2	A
P _C	Collector Dissipation ($T_C = 25^{\circ}C$)	80	W
Tj	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-65 ~ 150	٥C

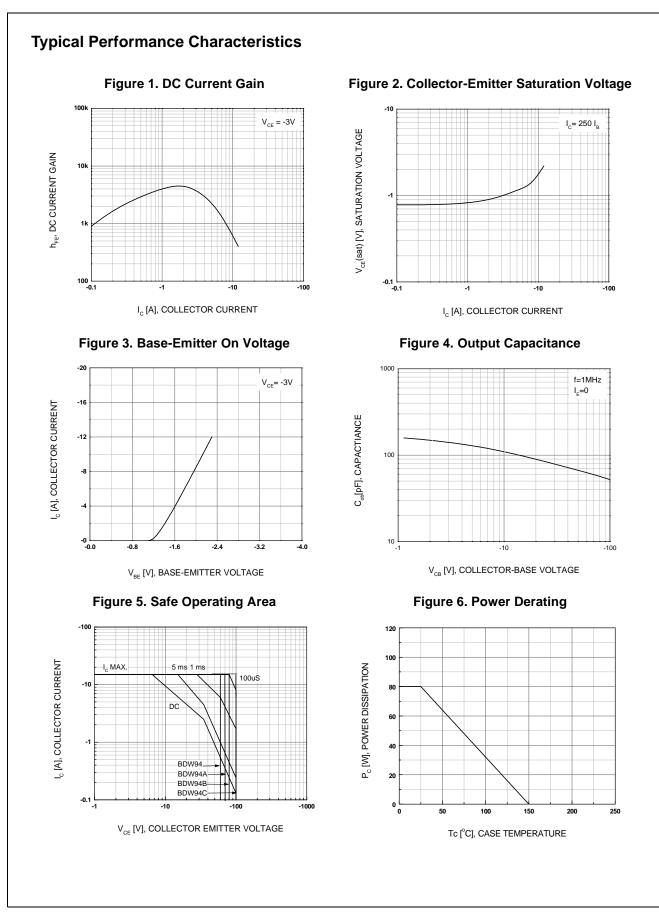
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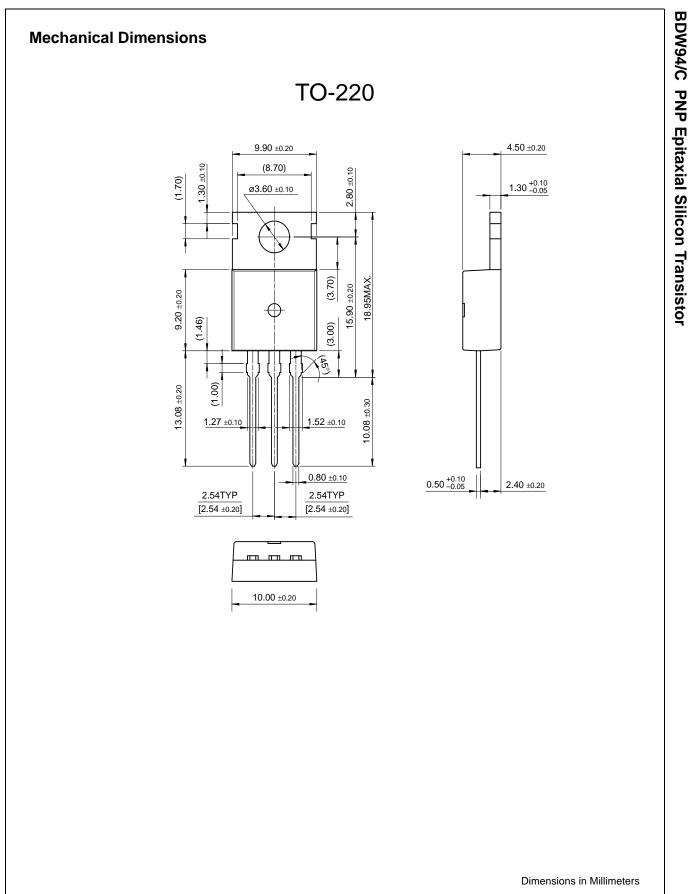
Symbol	Parameter	Conditions	Min.	Тур.	Max	Units
V _{CEO(sus)}	Collector-Emitter Sustaining Voltage : BDW94 : BDW94C	I _C = -100mA, I _B = 0	-45 -100			v v
I _{CBO}	Collector Cut-off Current : BDW94 : BDW94C	$V_{CB} = -45V, I_E = 0$ $V_{CB} = -100V, I_E = 0$			-100 -100	μΑ μΑ
I _{CEO}	Collector Cut-off Current : BDW94 : BDW94C	$V_{EB} = -45V, I_B = 0$ $V_{CE} = -100V, I_B = 0$			-1 -1	mA mA
I _{EBO}	Emitter Cut-off Current	V _{EB} = -5V, I _C = 0			-2	mA
h _{FE}	DC Current Gain *	$V_{CE} = -3V, I_C = -3A$ $V_{CE} = -3V, I_C = -5A$ $V_{CE} = -3V, I_C = -10A$	1000 750 100		20000	
V _{CE(sat)}	Collector-Emitter Saturation Voltage *	$I_{C} = -5A, I_{B} = -20mA$ $I_{C} = -10A, I_{B} = -100mA$			-2 -3	V V
V _{BE(sat)}	Base-Emitter Saturation Voltage *	$I_{C} = -5A, I_{B} = -20mA$ $I_{C} = -10A, I_{B} = -100mA$			-2.5 -4	V V
V _F	Parallel Diode Forward Voltage *	I _F = -5A I _F = -10A		-1.3 -1.8	-2 -4	V V

Electrical Characteristics

* Pulse Test: PW = $300\mu s$, Duty Cycle = 1.5% Pulsed







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Rev. 115